

Notice of Allowability	Application No.	Applicant(s)	
	10/605,679	CHEN, YI-NAN	
	Examiner	Art Unit	
	David Nhu	2818	
The MAILING DATE of this communication appeal All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this apport or other appropriate communication GHTS. This application is subject to	olication. If not included will be mailed in due course.	
1. This communication is responsive to <u>9/14/04</u> .			
2. The allowed claim(s) is/are 1-8.			
3. The drawings filed on 17 October 2003 are accepted by the	e Examiner.		
 4. ☐ Acknowledgment is made of a claim for foreign priority under a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 			
2. Certified copies of the priority documents have	been received in Application No	 •	
3. Copies of the certified copies of the priority doc	cuments have been received in this i	national stage application from	ı the
International Bureau (PCT Rule 17.2(a)).			
* Certified copies not received:			
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	•	complying with the requiremen	ıts
5. A SUBSTITUTE OATH OR DECLARATION must be subminFORMAL PATENT APPLICATION (PTO-152) which give	<u>.</u>		DF
6. CORRECTED DRAWINGS (as "replacement sheets") mus	t be submitted.		
(a) I including changes required by the Notice of Draftspers	on's Patent Drawing Review (PTO-	948) attached	
1) hereto or 2) to Paper No./Mail Date			
(b) including changes required by the attached Examiner's Paper No./Mail Date	s Amendment / Comment or in the C	ffice action of	
Identifying indicia such as the application number (see 37 CFR 1, each sheet. Replacement sheet(s) should be labeled as such in the			:
7. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT			
	Dar	102/2	
Attachment(s)		otant Application (DTO 152)	
1. Notice of References Cited (PTO-892)	<u> </u>	atent Application (PTO-152)	
2. Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summary Paper No./Mail Dat	•	1
3. Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date			
4. Examiner's Comment Regarding Requirement for Deposit	· <u> </u>	ent of Reasons for Allowance	
of Biological Material	9.		

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REASONS FOR ALLOWANCE

Claims 1-8 are allowed.

- 2. The following is an examiner's statement of reasons for allowance: None of the references of record teaches or suggests as cited in claim 1: ion bombarding an upper portion of said conformal silicon nitride protection layer; selectively etching away said ion bombarded upper portion of said conformal silicon nitride protection layer to expose an upper portion of said vertical sidewall of said deep trench, wherein remaining said conformal silicon nitride protection layer constitutes a silicon nitride hard mask protecting a lower portion of said deep trench; oxidizing said exposed upper portion of said vertical sidewall of said deep trench thereby forming a collar silicon oxide layer above said silicon nitride hard mask; selectively etching away said silicon nitride hard mask; using said collar silicon oxide layer as an etch mask to isotropic etching said vertical sidewall and said bottom surface of said deep trench that are not covered by said collar silicon oxide layer, thereby forming a bottle-shaped deep trench.
- 3. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

CONCLUSION

4. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure: Economikos et al (6,403,412 B1): Method for In-Situ Formation of Bottle Shaped Trench by Gas Phase Etching.

5. Any inquiry concerning this communication on earlier communications from the examiner should be directed to David Nhu, (571)272-1792. The examiner can normally be reached on Monday-Friday from 7:30 AM to 5:00 PM.

The examiner's supervisor, David Nelms can be reached on (571)272-1787.

The fax phone number for the organization where this application or proceeding is assigned is (571)273-1792.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

David Nhu

AN

September 29, 2004

DAVID NHU